

THz air-biased-coherent-detection spectrometer for material sensing





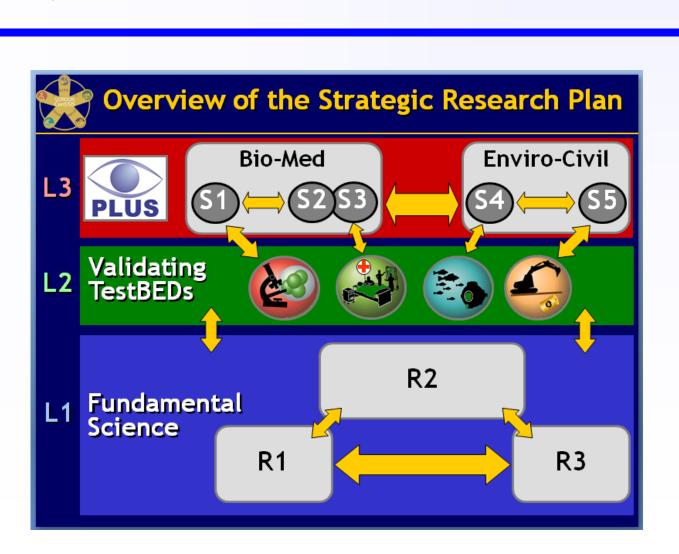
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- ► Compact THz platform ► Broad bandwidth 0.5~35 THz in 32 fs laser ► High peak THz field >100 kV/cm
 - ► High dynamic range >2000 ► Time-resolved spectroscopy ► Absorption-free material measurement

Abstract

Terahertz (THz) been the focus of imaging have considerable attention within standoff detection in explosives, weapons as well non-destructive evaluation of the broad-However, products. bandwidth and high-electric field for THz wave sensing and imaging are lagging behind the compelling needs for technology. We designed a reflective THz air-biased-coherentdetection (ABCD) spectrometer with a pulsed femtosecond laser amplifier.

A usable, continuous bandwidth from 0.5 THz to over 35 THz and a peak THz electrical field greater than 100 kV/cm are demonstrated. In addition, the compact and table-top THz-ABCD spectrometer provides an alternative to compete with the Fourier infrared (FTIR) transform spectrometer, which has been a major commercial product several decades.



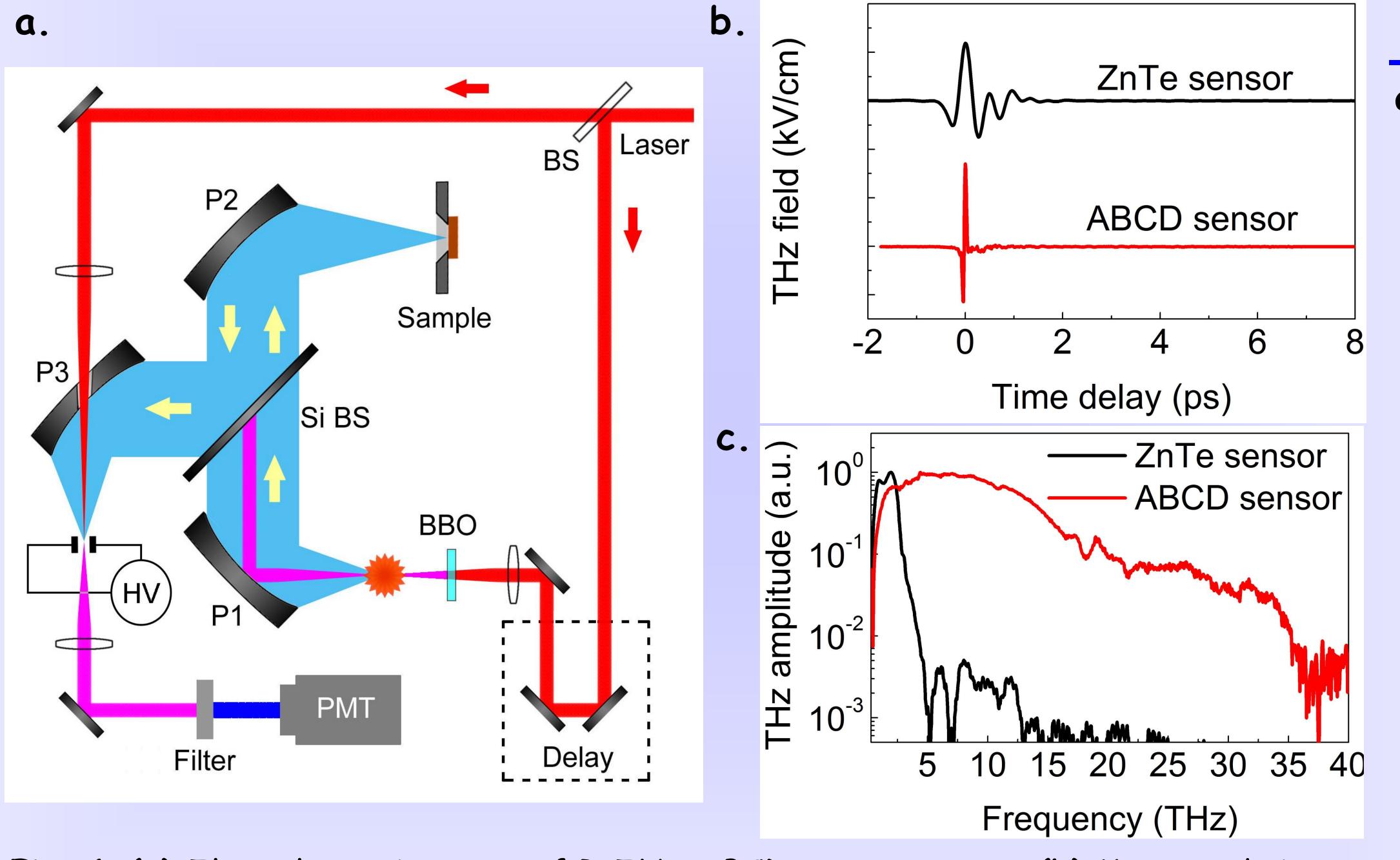


Fig. 1. (a) The schematic setup of R-THz-ABCD spectrometer. (b) Measured timedomain waveforms via conventional ZnTe sensor and via THz-ABCD sensor. (c) The Fourier transform spectra according to Fig. 1(b). Our group has successfully demonstrated ultra broadband THz spectroscopic measurements, covering a frequency range from 0.5 THz to 35 THz. This is one order of bandwidth improvement in comparison with conventional and commonly-used ZnTe sensor.

Acknowledgement

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References

- 1. I-C. Ho, X. Guo, X.-C. Zhang, Opt. Express 18, 2872 (2010).
- 2. J. Chen, X.-C. Zhang, etc, Opt. Express 15, 12060 (2007).

Experimental results

a. Explosives

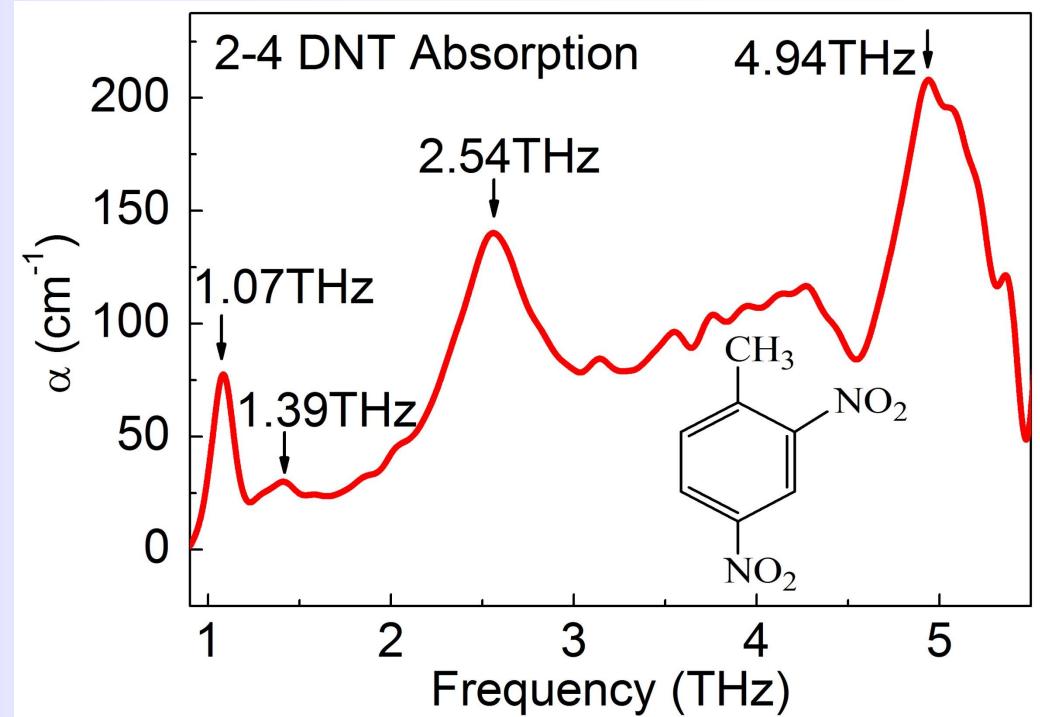


Fig. 2. The absorption spectrum of 2-4 DNT explosive.

b. Semiconductors

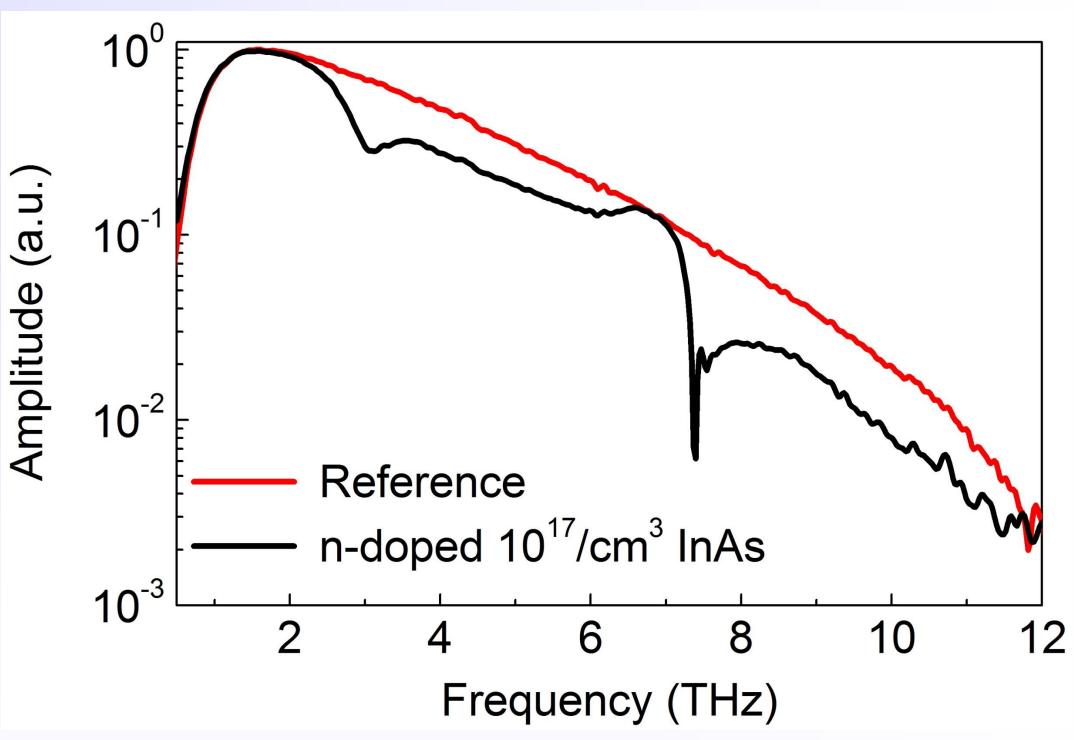


Fig. 3. The reflection spectrum of an ndoped $10^{17}/\text{cm}^3$ InAs crystal and the reference measured with an 85 fs pulse laser amplifier.